Thyristors

The Protection Products Group of World Products Inc., specializing in protection components for telecommunication and AC and DC circuits, is proud to feature World Products complete line of Thyristors.

At World Products Inc. we keep our promises. It's just that simple. You will see for yourself when you buy a World Products Thyristor that you have not only purchased a fine component, but that we will also provide the finest customer service in today's marketplace.

The main features of these Thyristors are:

- Bidirectional transient voltage protection.
- Nanosecond clamping response.
- No performance degradation under service life.
- Glass passivated junction.

Providing the following benefits:

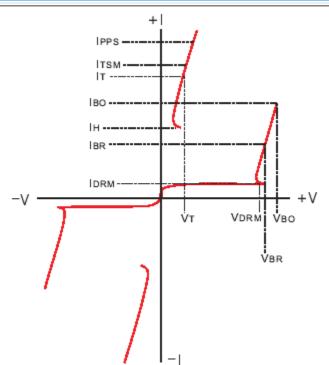
- Excellent voltage protection levels.
- Primary or secondary protection levels.
- Never needs replacement (no maintenance cost).
- Highest level of quality and reliability.
- Low cost auto-assembly.

Discover why the first choice in Thyristors is World Products.

Table of Contents

Definitions		
Application Notes	Features, Selection Guide, Maximum Thermal Ratings, Thermal Characteristics, Electrical Characteristics, Mechanical Data	
Maximum Surge Ratings		
Thyristor Electrical CharacteristicsAxial Lead and Surface Mount Electrical Characteristics		
Device Part Marking	Marking Codes, Order and Packing Information	
Rating and Characteristic Curves	Specifications	
Circuit Examples	Demonstration Circuits for Product Use	

Thyristors - Definitions



SYMBOL	CHARACTERISTIC	VALUE
V _{BO}	Max Breakover Voltage	The maximum voltage across the device in or at breakdown measured under a specified voltage and current rate of rise.
V _{BR}	Min Breakover Voltage	The minimum voltage at which the device switch-on begins and significant current flows.
I _{BO}	Breakover Current	The instantaneous current flowing at the breakover voltage. $(V_{ m BO})$
I _H	Holding Current	The minimum current required to maintain the device in the on-state.
I	On-state Current	The current through the device in the on-state condition.
V _T	On-state Voltage	The voltage across the device in the on-state condition at a specified current. (I_T)
V _{DRM}	Rated Repetitive Peak Off-state Voltage	Rated maximum (peak) continuous voltage that may be applied in the off-state condition.
I _{DRM}	Repetitive Peak Off-state Current	The maximum (peak) value of the current that results from the application of (V_{DRM})
I _{PPS}	Non-Repetitive Peak Pulse Current	Rated maximum value of peak impulse current of specified amplitude and waveshape that may be applied without damage to the device under test.
I _{TSM}	Non-Repetitive Surge Peak On-state Current	Rated maximum value of AC current, at a given frequency, which may be applied for specified time or number of cycles.
di/dt	Critical Rate of Rise of On-state Current.	Rated value of the rate of rise of current that the device can withstand without damage.
dv/dt	Critical Rate of Rise of Off-state Voltage.	The maximum rate of rise of voltage (below V _{DRM}) that will not cause switching from the off-state to the on-state

Thyristors - Application Notes

FEATURES

- Protects by Limiting voltages and shunting surge currents away from sensitive circuits.
- Designed for telecommunications applications such as line cards, modems, PBX, FAX, LAN, VHDSL.
- Helps meet standards such as GR1089, ITU K.20, IEC950, UL1459&50, FCC part 68.
- Low capacitance, High surge (A, B, C rating available), precise voltage limiting, Long life.

SELECTION GUIDE

Follow these steps to select the proper Thyristor surge protector for your application: **1.** Define the operating parameters for the circuit:

- Ambient operating temperature range
- Maximum telephone line operating current (highest battery and shortest copper loop)
- Maximum operating voltage: (Maximum DC bias + peak ringing voltage)
- Maximum surge current
- System voltage damage threshold

2. Select device with an off-state voltage rating (VDRM) above the maximum operating voltage at the minimum operating temperature

3. Select surge current ratings (I_{PPS} and I_{TSM}) \geq those which the application must withstand

4. Verify that the minimum holding current of the device at the maximum ambient temperature is above the maximum dc current of the system

5. Verify that the maximum breakover voltage of the device is below the system damage threshold.

6. Verify that the circuit's ambient operating temperatures are within the device's operating temperature range.

7. Verify that the device's dimensions fit the application's space considerations.

8. Independently evaluate and test the suitability and performance of the device in the application

MAXIMUM THERMAL RATINGS			
Rating	Symbol	Value	Unit
Storage Junction Temperature Range	Tstg	-50 to 150	°C
Operating Junction Temperature Range	TJ	-40 to 150	°C
Operating Ambient Temperature Range	ТА	-40 to 65	°C

Notes:

PCB board mounted on minimum foot print.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance Junction to leads TL on tab adjacent to plastic.			

Both leads soldered to identical pad sizes.

Røjl	Max.	20	$^{\circ}C$ / W	
,		-		

Notes:

The junction to lead thermal resistance represents a minimum limiting value with both leads soldered to a large near-infinite heatsink. The junction to ambient thermal resistance depends strongly on board mounting conditions and typically is 3 to 6 times higher than the junction to lead resistance. The data shown is to be used as guideline values for preliminary engineering.

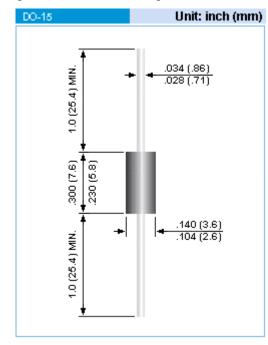
Thyristors - Application Notes - (Continued)								
ELECTRICAL C	HARACTERISTICS (Tc = 25 °C UNLESS OTHERWISE NOTED)							
Parameters	Test Conditions	Symbol	Min.	Max.	Unit			
On-State Current	$V_D = rated V_{DRM}$	Idrm		5	μA			
Breakover Current	f = 60 Hz, Isc = 1Arms, Vac = 1 KVrms, RL = 1Kohm, 1/2 AC cycle	Іво		800	mA			
Holding Current	$10/1000\mu$ s waveform, Isc = 10A, Voc = 62 V, RL = 400 ohms	Ін	150		mA			
	$IT = 1 A, Tw = 300 \mu s, 1 pulse$	VT		5	V			

Notes:

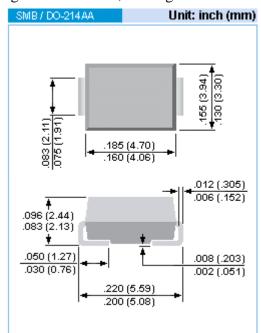
Specific I_H values are available by request.

MECHANICAL DATA

- Case: JEDEC DO-15 molded plastic
- Terminals: Plated Axial leads, Solder per MIL-STD-750, Method 2026
- Polarity: Bi-directional
- Weight: 0.015 ounce, 0.4 gram



- Case: JEDEC DO-214AA molded plastic
- Terminals: Solder plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Bi-directional Standard packaging: 12mm tape (EIA-481)
- Weight: 0.003 ounce, 0.093 gram



(T_J = 25 °C UNLESS OTHERWISE NOTED)

Rating		Non-Repetitive Peak Pulse Current						
Symbol			-	I _{PPS}			I _{TSM}	
Short-Circuit Current Wave	2/10 µs	8/20 µs	10/160 µs	5/310 µs	10/560 µs	10/1000 µs		
Open-Circuit Voltage Wave	2/10 µs	1.2/50 μs	10/160 µs	10/700 μs	10/560 µs	10/1000 µs		
Value A and SA Series	175 A	150 A	100 A	85 A	70 A	50 A	20 A	
Value B and SB Series	300 A	225 A	150 A	115 A	100 A	80 A	30 A	
Value C and SC Series	500 A	350 A	200 A	150 A	125 A	100 A	60 A	
Notes		(1,2,4,5,6)						

Notes:

1. Thermal accumulation between successive surge tests is not allowed.

2. The device under test initially must be in thermal equilibrium with $T_J = 25 \ ^{\circ}C$.

3. Test at 1 cycle, 60 Hz.

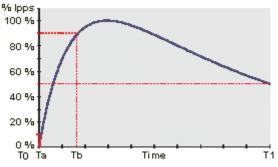
4. Surge ratings are non-repetitive because instantaneous junction temperatures may exceed the maximum rated T_J. Nevertheless, devices will survive many surge applications without degradation. Surge capability will not degrade over a device's typical operating life.

5. Adjust the surge generator for optimum current-wave accuracy when both voltage and current wave specifications cannot be exactly met. The current wave is more important than the voltage wave for accurate surge evaluation.

6. The waveform is defined as A/B ms where:

A: (Virtual front time) = 1.25 X Rise time = 1.25 X (T_b - T_a)

B: (Duration time to 50% level of I_{PPS}) = T₁ - T₀



Thyr	Thyristors - Electrical Characteristics										
	Rated Repetitive Peak Off-State Voltage	Breakover Voltage	On-state Voltage	Repetitive Peak Off-State Current	Breakover Current	Holding Current	Off-State Capacitance $(f = 1MHz, V_{ac} = 15 \text{ mV}_{rms})$		nce z,		
	Max.	Max.	Max.	Max.	Max.	Min.		Тур.			
Part	V _{DRM}	$V_{\rm BO}@I_{\rm BO}$	$V_T@1A$	I _{drm}	I _{BO}	I _H	C ₀ @ 2Vdc		'dc		
Number	V	V	V	μA	mA	mA		pF			
Series		A ar	nd SA, B ai	nd SB, C and SC	2		A SA	B SB	C SC		
TSP058¤¤	58	77	5.0	5.0	800	150	36	53	69		
TSP065¤¤	65	88	5.0	5.0	800	150	31	52	65		
TSP075¤¤	75	98	5.0	5.0	800	150	29	49	59		
TSP090¤¤	90	130	5.0	5.0	800	150	26	42	52		
TSP120¤¤	120	160	5.0	5.0	800	150	24	38	47		
TSP140¤¤	140	180	5.0	5.0	800	150	21	36	45		
TSP160¤¤	160	220	5.0	5.0	800	150	21	34	43		
TSP190¤¤	190	260	5.0	5.0	800	150	20	33	42		
TSP220¤¤	220	300	5.0	5.0	800	150	19	32	42		
TSP275¤¤	275	350	5.0	5.0	800	150	19	32	42		
TSP320¤¤	320	400	5.0	5.0	800	150	19	32	41		
Notes	(1,3)	(3,5,6)	(3)	(3)	(3)	(2,3)	(3)	(3)	(3)		

¤¤ Part Number Suffix:

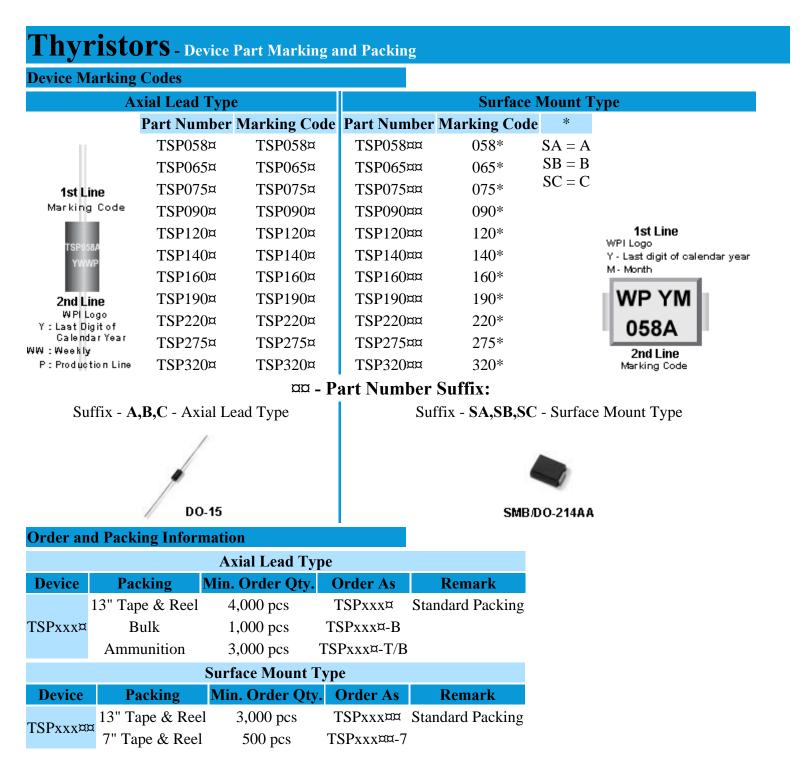
Suffix - **A,B,C** Axial Lead Type Suffix - SA,SB,SC Surface Mount Type



SMB/DO-214AA

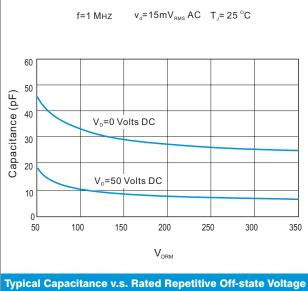
Notes:

- 1. Specific VDRM values are available by request.
- 2. Specific In values are available by request.
- **3.** All ratings and characteristics are at 25 °C unless otherwise specified.
- 4. VDRM applies for the life of the device. IDRM will be in spec during and following operation of the device.
- 5. VBO1 is at 100V/msec, Isc = $10A_{pk}$, Voc= $1KV_{pk}$, 10/1000 Waveform.
- 6. VB02 is at f = 60 Hz, Isc = 1 A(RMS), Vac = 1KV(RMS), RL = 1 Kohm, 1/2 AC cycle.

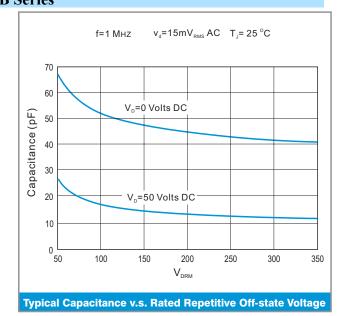


Thyristors - Rating and Characteristic Curves

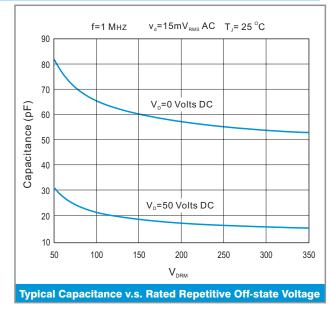
A and SA Series

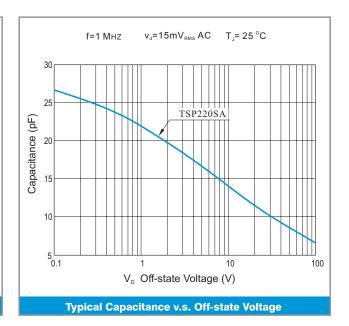


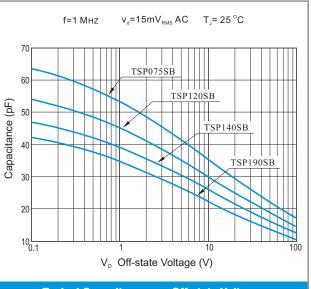




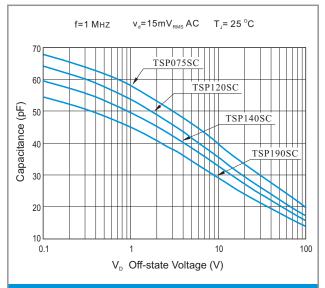








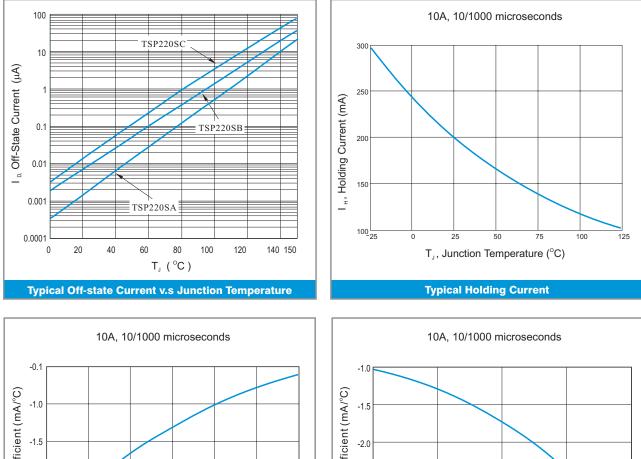


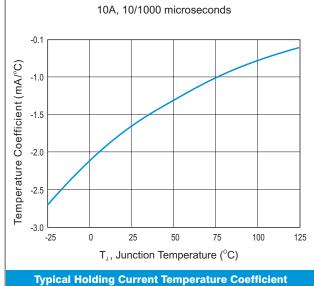


Typical Capacitance v.s. Off-state Voltage

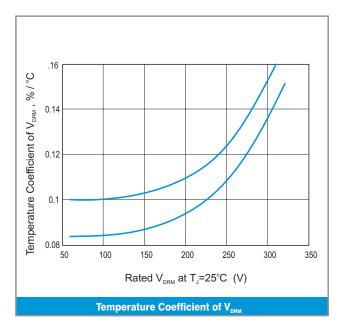
Thyristors - Rating and Characteristic Curves

A and SA Series - B and SB Series - C and SC Series



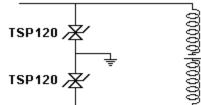


10A, 10/1000 microseconds

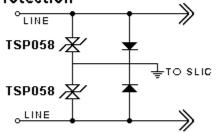


Thyristors - Circuit Examples

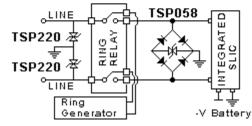
PABX Protection



SLIC Protection



Complete PC Board Operation Prot<u>ectio</u>n



DC Supply

